MASWSS0024



SPDT High Isolation Terminated Switch 0.01 - 3.0 GHz

Rev. V7

Features

Positive Voltage Control: 0 / +5 V High Isolation: 55 dB @ 0.9 GHz 50 dB @ 1.9 GHz

50 Ω Internal Terminations

Low Insertion Loss: 0.6 dB @ 0.9 GHz 0.7 dB @ 1.9 GHz

MSOP-8-EP Package

Description

The MASWSS0024 GaAs monolithic switch provides high isolation in a low cost, plastic surface mount package.

The MASWSS0024 is ideal for applications across a broad range of frequencies including synthesizer switching, transmit / receive switching, switch matrices and filter banks in systems such as radio and cellular equipment, PCS, GPS, and fiber optic modules.

M/A-COM Technology fabricates the MASWSS0024 using a 1.0-micron gate length MESFET process. The process features full chip passivation for performance and reliability.

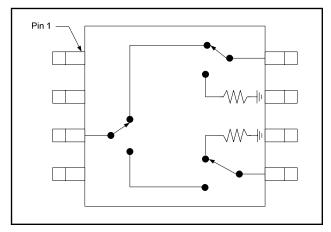
Ordering Information ¹

Commitment to produce in volume is not guaranteed.

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Part Number	Package	
MASWSS0024	Bulk Packaging	
MASWSS0024TR-3000	3000 piece reel	
MASWSS0024SMB	Sample Board	

1. Reference Application Note M513 for reel size information.

Functional Schematic ²



2. The exposed pad centered on the package bottom must be connected to RF and DC ground.

Pin Configuration

Pin No.	Function	Pin No.	Function
1	Control 1	5	RF Port 2
2	Control 2	6	Ground
3	RF Common	7	Ground
4	Ground	8	RF Port 1

Absolute Maximum Ratings ^{3,4}

Parameter	Absolute Maximum
Input Power (0.5 - 3.0 GHz) 3 V Control 5 V Control	+30 dBm +33 dBm
Operating Voltage	+8.5 Volts
Operating Temperature	-40°C to +85°C
Storage Temperature	-65°C to +150°C

- 3. Exceeding any one or combination of these limits may cause permanent damage to this device.
- 4. M/A-COM Technology does not recommend sustained operation near these survivability limits.

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Electrical Specifications: $T_A = 25^{\circ}C$, $V_C = 0 \text{ V} / 5 \text{ V}$, $Z_0 = 50 \Omega^5$

Parameter	Test Conditions	Units	Min.	Тур.	Max.
Insertion Loss	0.01 - 0.5 GHz 0.5 - 1.0 GHz 1.0 - 2.0 GHz 2.0 - 3.0 GHz	dB	_ _ _	0.5 0.6 0.7 0.75	0.7 0.8 —
Isolation	0.01 - 0.5 GHz 0.5 - 1.0 GHz 1.0 - 2.0 GHz 2.0 - 3.0 GHz	dB	 51 44 	59 57 53 43	_ _ _
Return Loss	0.01 - 0.5 GHz ⁶ 0.5 - 1.0 GHz 1.0 - 2.0 GHz 2.0 - 3.0 GHz	dB	_ _ _	20 20 20 20	_ _ _ _
Input IP ₂	2-Tone, 900 MHz, 5 MHz spacing	dBm	_	83	_
Input IP ₃	2-Tone, 900 MHz, 5 MHz spacing	dBm	_	43	_
Trise, Tfall	10% to 90% RF & 90% to 10% RF	ns	_	24	_
Input P1dB Compression	$V_C = 0 \text{ V/5.0 V, 1 GHz}$ $V_C = 0 \text{ V/3.0 V, 1 GHz}$	dBm	_	29 17.5	_
Ton, Toff	50% of $V_{\text{\scriptsize C}}$ to 10% / 90% RF	ns	_	15	_
Transients	In-band	mV		12	
Control Current	V _C = 5 V	μΑ	_	2	13

^{5.} External DC blocking capacitors are required on all RF ports (47 pF capacitors are recommended). Use larger value capacitors for lower frequency operation (e.g. use 10,000 pF capacitors to optimize insertion and return loss at frequencies below 50 MHz).

Truth Table

V1	V2	RFC-RF1	RFC-RF2
0	1	Off	On
1	0	On	Off

Logic Level	Voltage Level
V _{LOW} "0"	0 ± 0.2 V
V _{HIGH} "1"	3.0 V to 8.0 V

Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

^{6.} Terminated return loss is governed by blocking capacitors internal to the device; see applications plot.

MASWSS0024

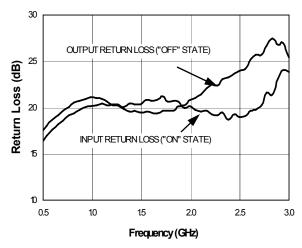


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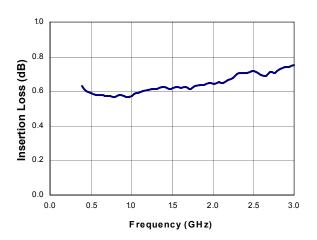
Rev. V7

Typical Performance Curves

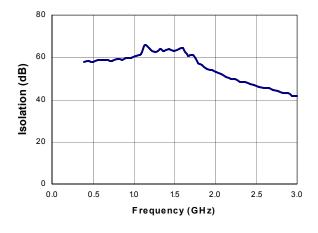
Return Loss



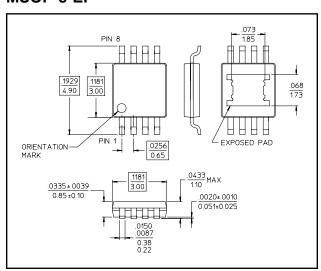
Insertion Loss



Isolation



MSOP-8-EP



† Meets JEDEC moisture sensitivity level 1 requirements. Plating is 100% matte tin over copper.

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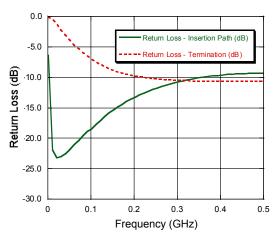
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Rev. V7

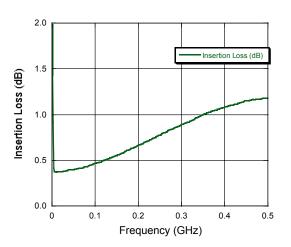
Applications Section

Typical Performance Curves, Very Low Frequency, 10000 pF Blocking Capacitors

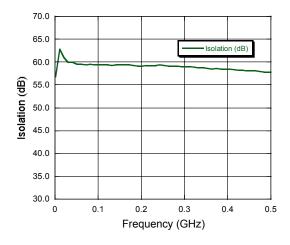
Return Loss vs. Frequency



Insertion Loss vs. Frequency



Isolation vs. Frequency



ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions